

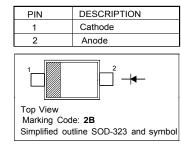


Surface Mount Schottky Barrier Diodes

Features

Low Forward Voltage

PINNING



Absolute Maximum Ratings (T_a = 25 °C)

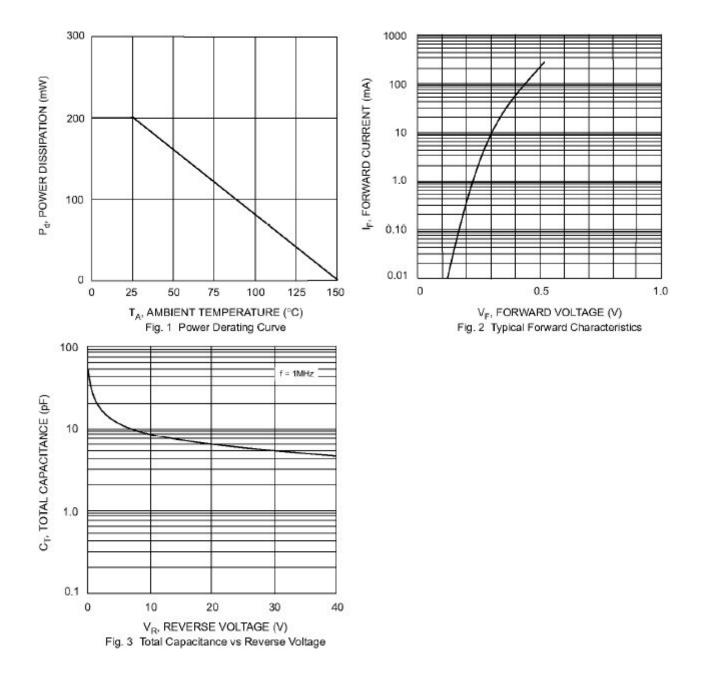
Parameter	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	30	V
Reverse Voltage	V _R	30	V
Average Forward Rectified Current	I _{F(AV)}	300	mA
Non-Repetitive Peak Forward Surge Current at t = 1 s	I _{FSM}	2	А
Power Dissipation	P _{tot}	200	mW
Operating and Storage Temperature Range	T _j , T _{stg}	- 65 to + 125	°C

Characteristics at T_a = 25 °C

Parameter	Symbol	Min.	Тур.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 10 \text{ yA}$	V _{(BR)R}	30	-	-	V
Reverse Leakage Current at V _R = 30 V	I _R	-	-	5	μA
Forward Voltage at I _F = 20 mA at I _F = 200 mA	V _F	-	-	0.37 0.6	V
Total Capacitance at $V_R = 0 V$, f = 1 MHz	C _T	-	50	-	pF
Reverse Recovery Time at I _F = I _R = 200 mA, I _{rr} = 0.1 I _R , R _L = 100 Ω	t _{rr}	-	10	-	ns



MA729



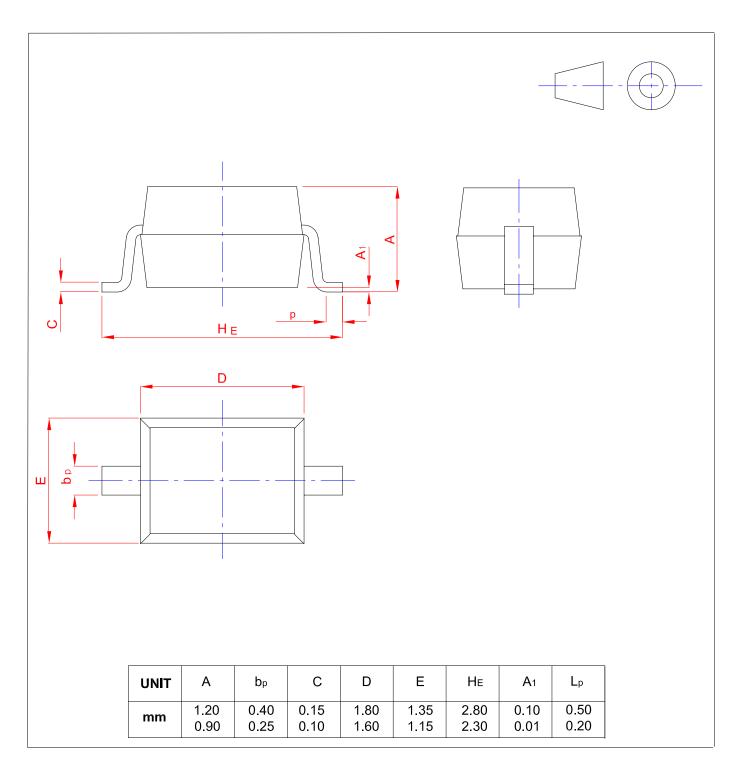


MA729

SOD-323

PACKAGE OUTLINE

Plastic surface mounted package; 2 leads



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